

/ Descriptions

Silicon NPN transistor in a SOT-89 Plastic Package.

/ Features

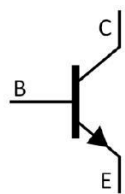
BR2SB1424Q AEC-Q101

Low $V_{CE(sat)}$,excellent current gain characteristic, Complementary to BR2SB1424Q, Qualified to AEC-Q101 Standards for High Reliability, HF Product.

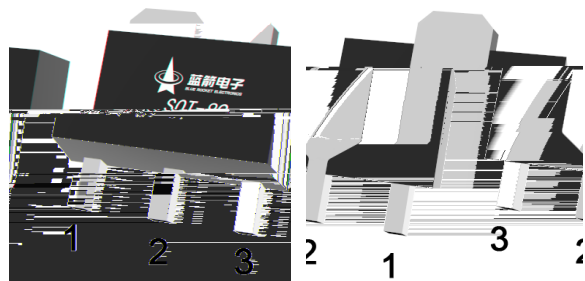
/ Applications

General purpose amplifier, Meet the stringent requirements of automotive applications.

/ Equivalent Circuit



/ Pinning



PIN1 Base PIN 2 Collector PIN 3 Emitter

/ h_{FE} Classifications & Marking

h_{FE} Classifications Symbol	Q	R	S	E
h_{FE} Range	120 270	180 390	270 560	390 820
Marking	QCFQ*	QCFR*	QCFS*	QCFE*

/ Absolute Maximum Ratings(Ta=25)

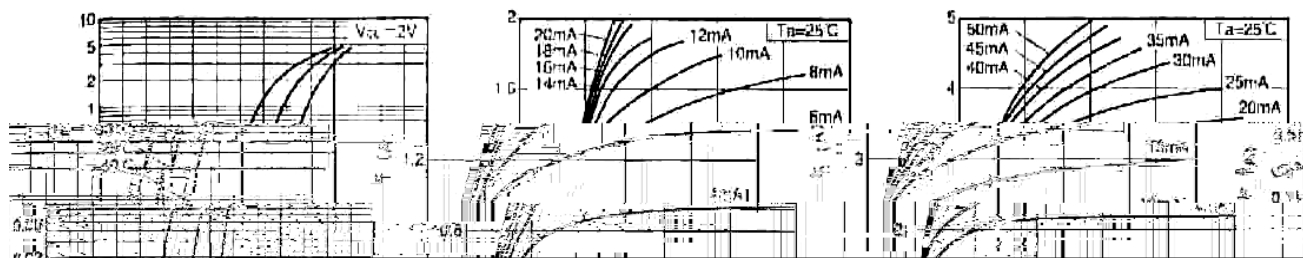
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V _{CBO}	40	V
Collector to Emitter Voltage	V _{CEO}	20	V
Emitter to Base Voltage	V _{EBO}	6.0	V
Collector Current-Continuous	I _{C(DC)}	3.0	A
Collector Base-Continuous(Pulse)*	I _{C(Pulse)*}	5.0	A
Collector Power Dissipation	P _C	500	mW
Junction Temperature	T _j	150	
Storage Temperature Range	T _{stg}	-55 150	

*:Single pulse P_w=10ms

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V _{CBO}	I _C =50μA	40			V
Collector to Emitter Breakdown Voltage	V _{CEO}	I _C =1.0mA	20			V
Emitter to Base Breakdown Voltage	V _{EBO}	I _E =50μA	6.0			V
Collector Cut-Off Current	I _{CBO}	V _{CB} =30V			0.1	μA
Emitter Base Cut-Off Current	I _{EBO}	V _{EB} =5.0V			0.1	μA
DC Current Gain	h _{FE}	V _{CE} =2.0V I _C =100mA	180		560	
Collector to Emitter Saturation Voltage	V _{CE(sat)}	I _C =2.0A I _B =100mA		0.2	0.5	V
Transition Frequency	f _T	V _{CE} =2.0V I _C =0.5A f=100MHz		290		MHz
Collector Output Capacitance	C _{ob}	V _{CB} =10V I _E =0 f=1.0MHz		25		pF

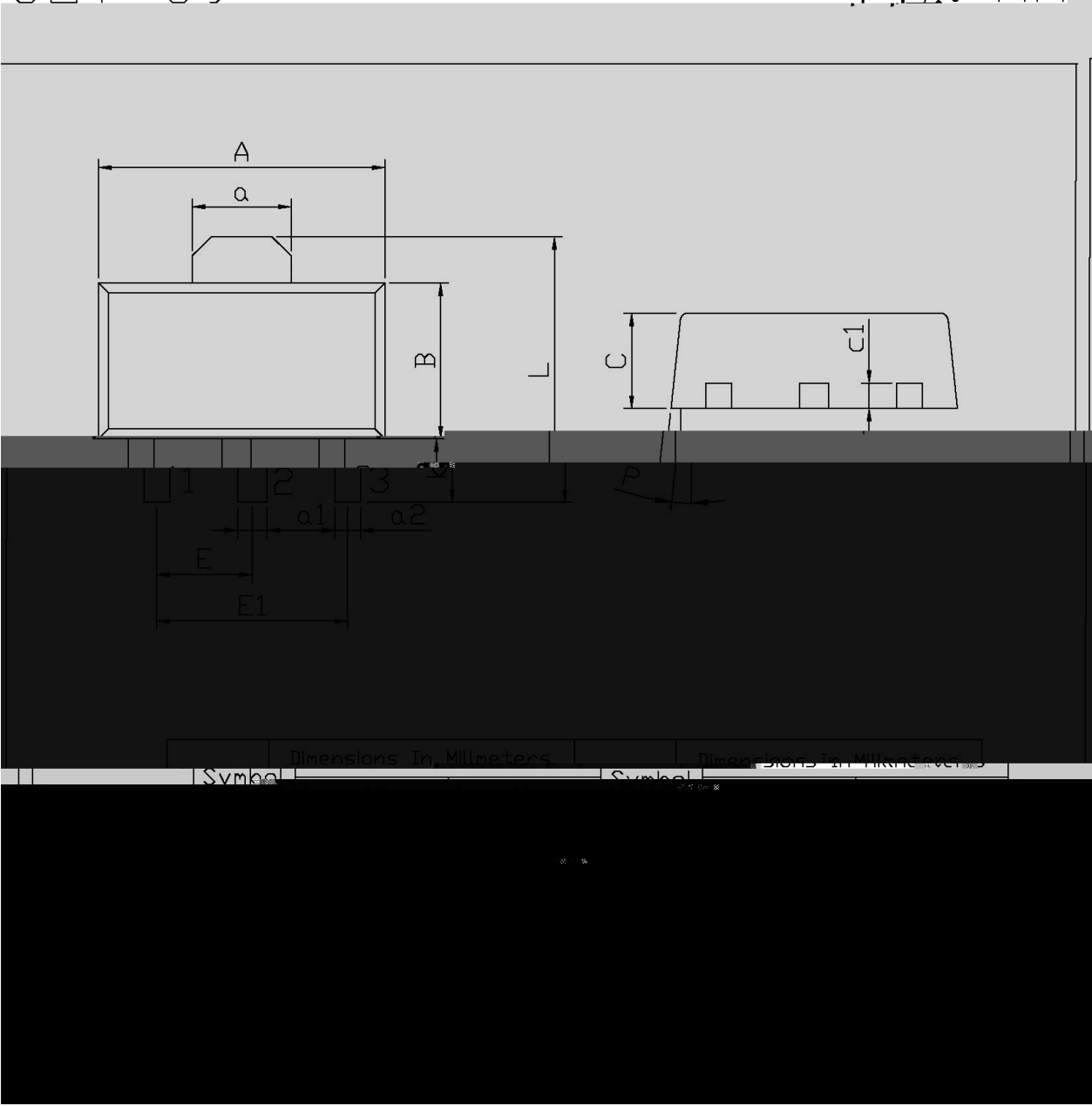
/ Electrical Characteristic Curve



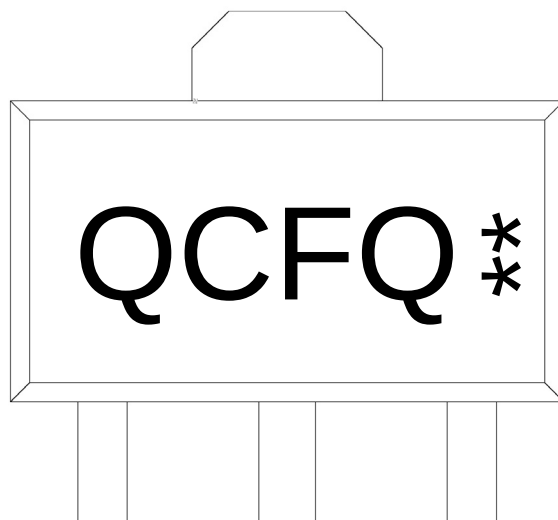
/ Package Dimensions

SOT-89

单位: mm



/ Marking Instructions



Q

CF

Q: h_{FE}

Note:

Q: Automobile halogen-free product Code

CF: Product Type

Q h_{FE} Classifications Symbol

** : Lot No. Code, code change with Lot No

() / **Temperature Profile for IR Reflow Soldering(Pb-Free)**

Note:

- | | | | | | |
|---|-----|-----|----|----------|---|
| 1 | 150 | 200 | 60 | 120sec; | 1.Preheating:150~200 , Time:60~120sec. |
| 2 | 255 | 5 | 5 | 0.5sec; | 2.Peak Temp.:255 5 , Duration:5 0.5sec. |
| 3 | | | 2 | 10 /sec. | 3. Cooling Speed: 2~10 /sec. |

/ **Resistance to Soldering Heat Test Conditions**

260 5 10 1 sec. Temp.:260±5 Time:10±1 sec

/ **Packaging SPEC.**

/ REEL

Package Type	Units					Dimension (unit mm ³)		
	Units/Reel /	Reels/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Reel	Inner Box	Outer Box